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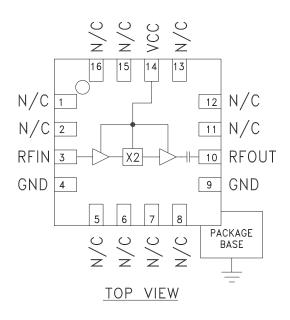
# SMT GaAs HBT MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 9.9 - 12.7 GHz OUTPUT

#### **Typical Applications**

Active Multiplier for X Band Applications:

- OC-192 Clock Recovery
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Test Instrumentation

#### **Functional Diagram**



#### **Features**

Output Power: +4 dBm

Sub-Harmonic Suppression: 30 dBc SSB Phase Noise: -142 dBc/Hz

Single Supply: 5V@ 46 mA

16 Lead 3x3mm SMT Package: 9mm²

#### **General Description**

The HMC369LP3 & HMC369LP3E are active miniature x2 frequency multipliers utilizing InGaP GaAs HBT technology in 3x3 mm leadless QFN surface mount packages. Power output is +4 dBm typical from a single +5V supply and varies little vs. input power, temperature and supply voltage. Suppression of undesired fundamental and sub-harmonics is 30 dBc typical with respect to output signal level. The low additive SSB phase noise of -142 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance. The HMC369LP3(E) is ideal for use in LO multiplier chains allowing reduced parts count versus traditional approaches. The HMC-369LP3(E) are also useful for OC-192 clock recovery. The application of 10 GBPS data to the input generates a -7 dBm clock tone at the output with spurious signals suppressed by 25 dB.

## Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc = 5V

Parameter		Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, Input		4.95 - 5.3		5.3 - 6.35			GHz	
Frequency Range, Output		9.9 - 10.6		10.6 - 12.7			GHz	
Input Power Range		-5		+5	-5		+5	dBm
Output Power		-1	3		0	4		dBm
Sub-Harmonic Suppression			30			30		dBc
Input Return Loss			17			16		dB
Output Return Loss			5.5			6		dB
SSB Phase Noise (100 kHz Offset) Pin:	= 0 dBm		-142			-142		dBc/Hz
Supply Current (Icc)			46	61		46	61	mA

## HMC369\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

## COMPARABLE PARTS 🖵

View a parametric search of comparable parts.

#### **EVALUATION KITS**

• HMC369LP3 Evaluation Board

#### **DOCUMENTATION**

#### **Data Sheet**

• HMC369 Data Sheet

#### **TOOLS AND SIMULATIONS**

HMC369 S-Parameter

## REFERENCE MATERIALS 🖵

#### **Quality Documentation**

- Package/Assembly Qualification Test Report: 16L 3x3mm QFN Package (QTR: 11003 REV: 02)
- Package/Assembly Qualification Test Report: LP2, LP2C, LP3, LP3B, LP3C, LP3D, LP3F, LP3G (QTR: 2014-0364)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

## DESIGN RESOURCES 🖵

- HMC369 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

#### **DISCUSSIONS**

View all HMC369 EngineerZone Discussions.

#### SAMPLE AND BUY 🖳

Visit the product page to see pricing options.

#### **TECHNICAL SUPPORT**

Submit a technical question or find your regional support number.

#### DOCUMENT FEEDBACK $\Box$

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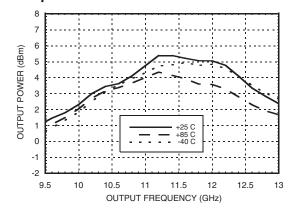


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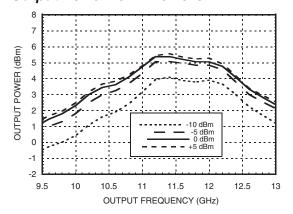


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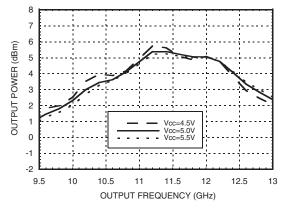
## Output Power vs. Temperature @ 0 dBm Drive Level



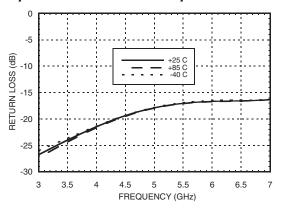
#### **Output Power vs. Drive Level**



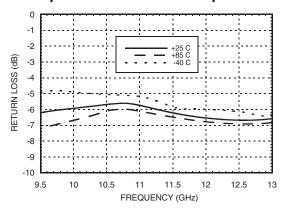
#### Output Power vs. Supply Voltage @ 0 dBm Drive Level



#### Input Return Loss vs. Temperature



#### Output Return Loss vs. Temperature



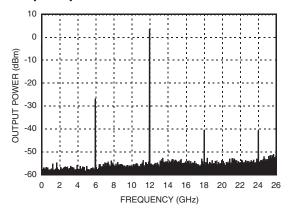


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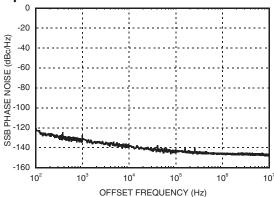


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#### **Output Spectrum**



SSB Phase Noise Performance, Fout= 10.66 GHz, Input Power= 0 dBm





RoHS (E)

# SMT GaAs HBT MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 9.9 - 12.7 GHz OUTPUT

#### **Absolute Maximum Ratings**

RF Input (Vcc = +5V)	+20 dBm
Vcc	+5.5V
Channel Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 6.8 mW/°C above 85 °C)	440 mW
Thermal Resistance (R <sub>th</sub> ) (junction to ground paddle)	147.8 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

#### Typical Supply Current vs. Vcc

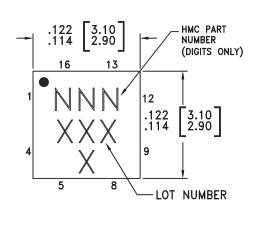
Vcc (V)	Icc (mA)		
4.5	45		
5.0	46		
5.5	47		

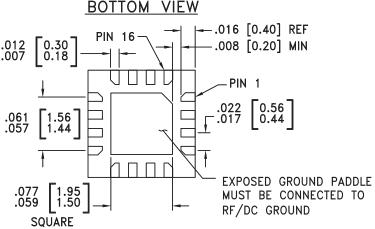
Note: Multiplier will operate over full voltage range shown above.

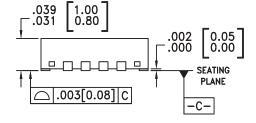


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing**







#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
   PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC369LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	369 XXXX
HMC369LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	3 <u>69</u> XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260  $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX



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# SMT GaAs HBT MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 9.9 - 12.7 GHz OUTPUT

#### **Pin Description**

Pin Number	Function	Description	Interface Schematic
1, 2, 5 - 8, 11 - 13, 15, 16	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RFIN	RF input needs to be DC blocked only if there is an external DC voltage applied to RFIN.	RFIN 0————————————————————————————————————
4, 9	GND	All ground leads and ground paddle must be soldered to PCB RF/DC ground.	Ģ GND =
10	RFOUT	Multiplied Output. AC coupled. No external DC blocks necessary.	—
14	Vcc	Supply voltage 5V ± 0.5V.	

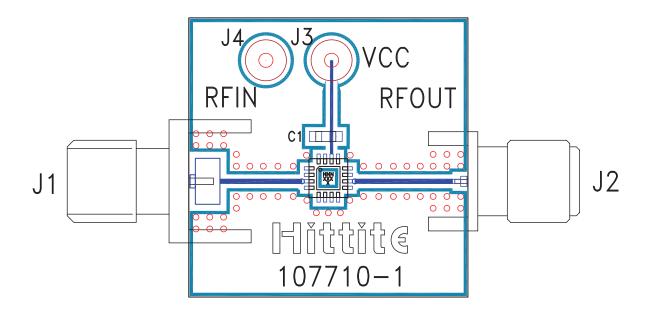


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## SMT GaAs HBT MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 9.9 - 12.7 GHz OUTPUT

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 107712 [1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Pin
C1	0.01 μF Capacitor, 0603 Pkg.
U1	HMC369LP3 / HMC369LP3E x2 Active Multiplier
PCB [2]	107710 Eval Board

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. The evaluation circuit board shown is available from Hittite upon request.